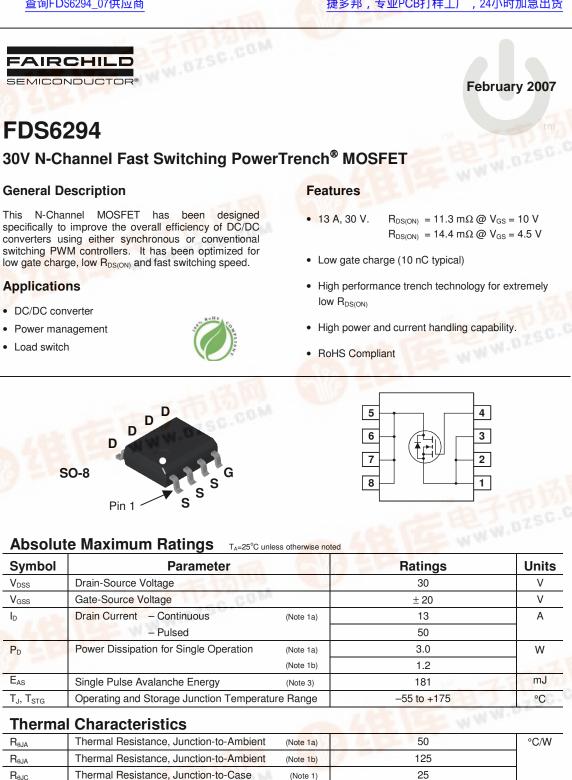
# 查询FDS6294\_07供应商

# 捷多邦,专业PCB打样工厂,24小时加急出货

FDS6294



# Package Marking and Ordering Information

Device Marking	Device	Reel Size	Tape width	Quantity
FDS6294	FDS6294	13"	12mm	2500 units
	•		•	•

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 $V_{\text{DSS}}$ 

V<sub>GSS</sub>

 $I_D$ 

PD

E<sub>AS</sub>

 $R_{\theta JA}$ 

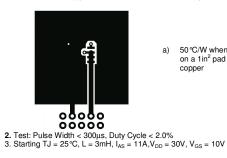
R<sub>0JA</sub>  $R_{\theta JC}$ 

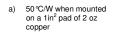


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Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
				- 76		•
	acteristics		L			
BVDSS	Drain–Source Breakdown Voltage	$V_{GS} = 0 V$ , $I_D = 250 \mu A$	30			V
<u>ΔBVdss</u> ΔTj	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$ , Referenced to $25^{\circ}\text{C}$		27		mV/°C
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{\text{DS}} = 24 \text{ V}, \qquad V_{\text{GS}} = 0 \text{ V}$			1	μA
I <sub>GSS</sub>	Gate-Body Leakage	$V_{\text{GS}}=\pm~20~V, V_{\text{DS}}=0~V$			±100	nA
On Chara	acteristics (Note 2)					
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{\text{DS}} = V_{\text{GS}}, \qquad I_{\text{D}} = 250 \; \mu\text{A}$	1	1.8	3	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, Referenced to $25^{\circ}$ C		-5		mV/°C
R <sub>DS(on)</sub>	Static Drain–Source	$V_{GS} = 10 \text{ V}, \qquad I_D = 13 \text{ A}$		9.4	11.3	mΩ
	On-Resistance	$V_{GS}=4.5~V, \qquad I_{D}=12~A$		11.5	14.4	
		$V_{GS}$ = 10 V, $I_D$ = 13 A, $T_J$ =125°C		13.5	16.5	
I <sub>D(on)</sub>	On–State Drain Current	$V_{GS} = 10 \text{ V}, \qquad V_{DS} = 5 \text{ V}$	50			A
<b>g</b> <sub>FS</sub>	Forward Transconductance	$V_{DS} = 10 V$ , $I_{D} = 13 A$		48		S
Dynamic	Characteristics					
Ciss	Input Capacitance	$V_{DS} = 15 V$ , $V_{GS} = 0 V$ ,		1205		pF
Coss	Output Capacitance	f = 1.0 MHz		323		pF
C <sub>rss</sub>	Reverse Transfer Capacitance			102		pF
R <sub>G</sub>	Gate Resistance	$V_{GS} = 15 \text{ mV}, \text{ f} = 1.0 \text{ MHz}$		0.9		Ω
Switchin	g Characteristics (Note 2)					
t <sub>d(on)</sub>	Turn–On Delay Time	$V_{DD} = 15 V$ , $I_D = 1 A$ ,		9	18	ns
tr	Turn–On Rise Time	$V_{GS} = 10 \text{ V}, \qquad R_{GEN} = 6 \Omega$		4	8	ns
t <sub>d(off)</sub>	Turn-Off Delay Time			24	48	ns
t <sub>f</sub>	Turn–Off Fall Time			6	12	ns
Qg	Total Gate Charge	$V_{DS} = 15 V$ , $I_{D} = 13 A$ ,		10	14	nC
Q <sub>gs</sub>	Gate-Source Charge	$V_{GS} = 5 V$		3.5		nC
Q <sub>gd</sub>	Gate-Drain Charge	]		3		nC
Drain-So	ource Diode Characteristics	and Maximum Ratings				
ls	Maximum Continuous Drain-Source	•			2.1	Α
V <sub>SD</sub>	Drain-Source Diode Forward Voltage	$V_{GS} = 0 V$ , $I_{S} = 2.1 A$ (Note 2)		0.74	1.2	V
t <sub>rr</sub>	Diode Reverse Recovery Time	$I_F = 13 \text{ A}, d_{iF}/d_t = 100 \text{ A}/\mu \text{s}$		25		nS
Q <sub>rr</sub>	Diode Reverse Recovery Charge			14		nC

1. R<sub>8JA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R<sub>eJC</sub> is guaranteed by design while R<sub>eCA</sub> is determined by the user's board design.





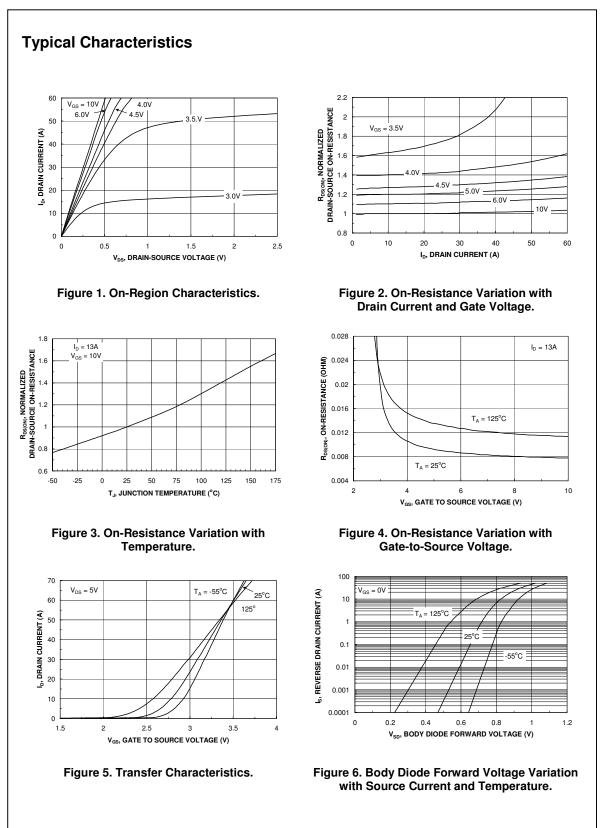


b) 125°C/W when mounted on a minimum pad.

Scale 1 : 1 on letter size paper

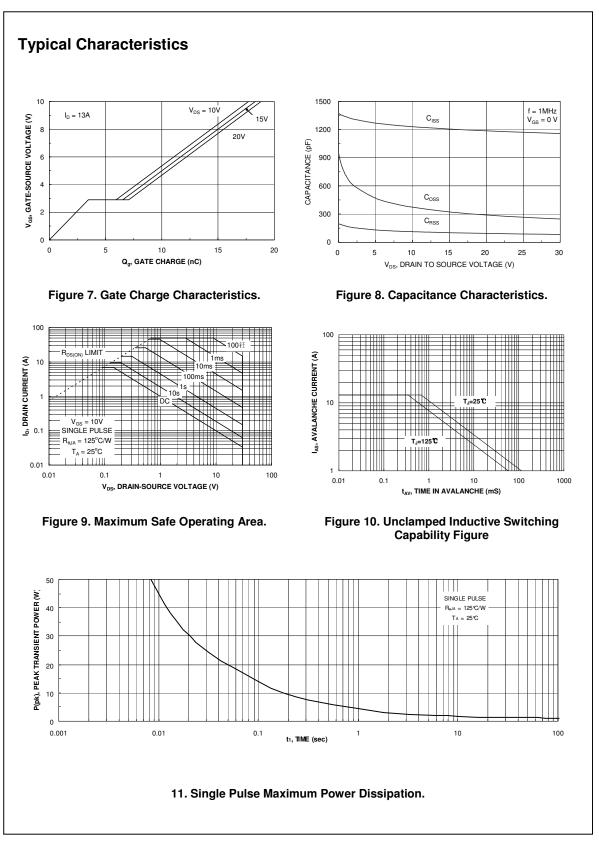
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FDS6294

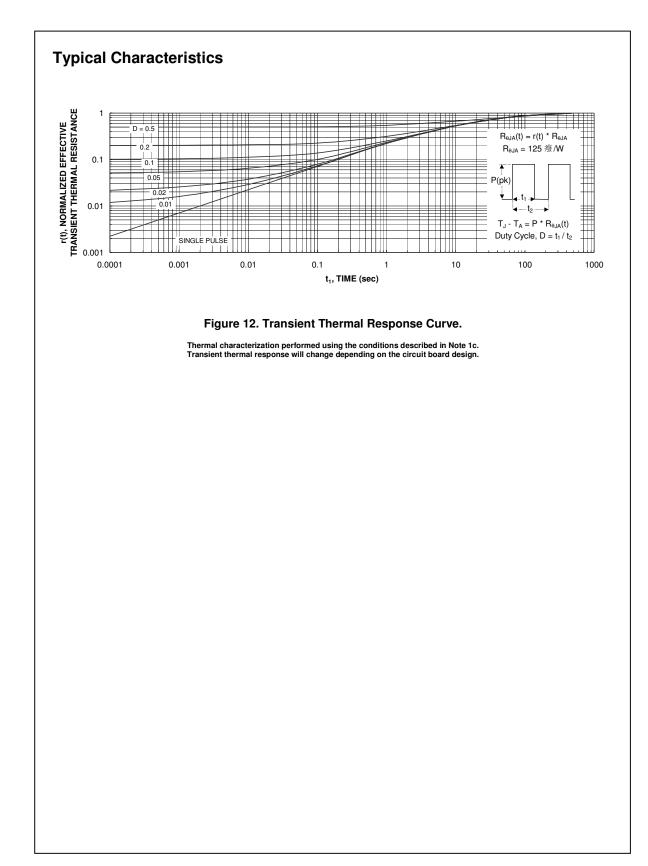


# FDS6294

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